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## REVIEW

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# Large-area perovskite solar cells – a review of recent progress and issues

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In recent years, perovskite solar cells (PSCs) have attracted great attention in the photovoltaic research field, because of their high-efficiency (certified 22.1%) and low-cost. In this review paper, we briefly introduce the history of efficiency development for PSCs, and discuss some of the major problems for large-area ( $\geq 1 \text{ cm}^2$ ) PSC devices. In addition, we summarize the recent progress in the aspects of fabrication methods for large-area perovskite films, and improving the efficiency and stability of the large-area PSC devices. Finally, we give a short summary and outlook of large-area PSC devices. This article is mainly organized into three parts. The first part focuses on the main fabricating technologies for large-area perovskite films. The second section discusses some methods that are used to improve the efficiency of PSCs. In the last part, different approaches are used to improve the stability of PSCs.

#### 1. Introduction

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Due to the growing population, the global energy demand is increasing year by year. Moreover, the global energy demand is predicted to double by 2050.<sup>1,2</sup> Thus, the development of renewable energy becomes an imminent requirement, such as water energy, wind energy, and solar energy. The photovoltaic power generation capacity is installed to be 303 GW and increased 75 GW in 2016. In 2016, photovoltaic power generation accounted for only 1.5% of the world's total electricity generation. So high performance, long-term stability, low cost and environmental friendly solar cells become the focus of current energy research.

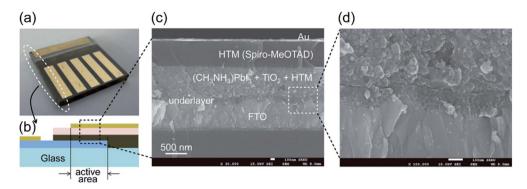
PSCs have attracted great attention in photovoltaic research in recent years, because of their high-efficiency (certified 22.1%)<sup>3</sup> and low-cost. Meanwhile, organic–inorganic perovskites have a high optical absorption coefficient<sup>4</sup> and the diffusion lengths exceed 1  $\mu$ m for electrons and holes.<sup>5</sup> So, organic–inorganic perovskite is an ideal absorber material for solar cells,<sup>6-19</sup> photodetectors,<sup>20–22</sup> light-emitting diodes,<sup>23–26</sup> etc.

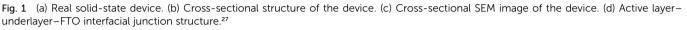
In recent years, hybrid metal halide perovskite materials have revolutionized the field of photovoltaics materials research, due to the power conversion efficiency (PCE) of PSC devices having been rapidly improved, from the point 3.8% in 2009,<sup>6</sup> up to 22.6% in 2017 (ref. 3) (certified 22.1%).<sup>3</sup> It attracted attention of researchers working on various photovoltaic technologies, especially dye solar cells (DSCs) and organic photovoltaic (OPV) with emphasis on better efficiency. In 2009, T. Miyasaka et al.6 has creatively made CH<sub>3</sub>NH<sub>3</sub>PbBr<sub>3</sub>/TiO<sub>2</sub>-based and CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub>/TiO<sub>2</sub>-based DSCs, the PCE of the cells is 3.13% and 3.81%, respectively. The PSCs attracted researchers' attention then happened in 2012, when M. Grätzel and N. G. Park et al.27 made PSCs device using perovskite films as the photoactive absorber layer, the mp-TiO<sub>2</sub> and spiro-MeOTAD were used as the electron transport layer (ETL) and hole transport layer (HTL), respectively (Fig. 1), achieving the PCE of 9.7%. In 2013, M. Z. Liu, M. B. Johnston and H. J. Snaith<sup>8</sup> fabricated planar heterojunction PSCs via vapor deposition, and the efficiency of the PSCs device is up to 15.4%. The yttrium (Y) doping the  $TiO_2$  (ETL) improves the electron transport channel in the PSCs device, and increase its carrier concentration and modify the ITO electrode to reduce its work function. These changes achieved a PCE of 19.3%.28 In 2015, S. I. Seok et al.29 attained an efficiency of PSCs up to 20.1%. In 2016, A. Zettl et al.<sup>30</sup> made an architecture of GaN/CH<sub>3</sub>NH<sub>3</sub>SnI<sub>3</sub>/monolayer h-BN/CH<sub>3</sub>NH<sub>3</sub>-PbI<sub>3-x</sub>Br<sub>x</sub>/HTL and graphene aerogel/Au (Fig. 2). The graded bandgap PSCs demonstrated with PCE averaging 18.4%, with a best of 21.7%. Other researchers, E. H. Sargent et al.<sup>31</sup> (2017) achieved the certified efficiencies of 20.1% via contactpassivation strategy, retaining 90% (97% after dark recovery) of their initial PCE after 500 hours of continuous roomtemperature. Meanwhile, E. K. Kim, J. H. Noh, and S. I. Seok et al.3 reported that the introduction of additional iodide ions into the organic cation solution, that was used to form the perovskite layers through an intramolecular exchanging process and decrease the concentration of deep-level defects. The certified PCE of PSCs attained 22.1%.3

In addition, high efficiency PSCs devices include not only small devices, but also larger cells. A PSCs device with area of large-area ( $\geq 1 \text{ cm}^2$ ) and maximum PCE of 20.5% (certified

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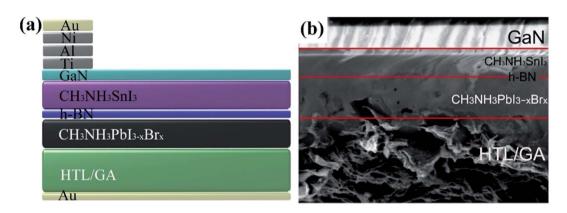


Fig. 2 (a) Cross-sectional schematic. (b) SEM images of perovskite cell with integral monolayer h-BN and graphene aerogel.<sup>30</sup>

19.7%) has been reported.<sup>3</sup> Table 1 shows some results for largearea PSCs have been reported in the literatures.

But, for large-area PSCs device, it still has some issues need to be solved, namely fabrication, stability, hysteresis, fabrication cost and environmental concerns. Such as, the continuous fabrication of cracks-free and pinholes-free the perovskite and the selective carrier extraction layers films is difficulty with large-area PSCs devices. The dilemma with optimizing such charge carrier extraction layers in solar cells is that the film should be thin to minimize resistive losses, while at the same time, it should cover the entire collector area in a contiguous and uniform manner.48 In the large-area PSCs device, surfaces, bulk defects and interfaces introduce recombination centers that lead to fast nonradiative losses,49 and interface losses, which lead to the  $V_{\rm oc}$ ,  $J_{\rm sc}$  and fill factor (FF) decrease. Meanwhile, the perovskite material is easily thermal decomposition and hydrodecomposition, that leads to the lack of stability for PSCs device. The poor stability of the perovskite materials and devices is a big challenge, which hinder the PSCs device could be transferred from the laboratory to industry and outdoor applications. Thus, for large-area PSCs device, the major challenges relate to the improving efficiency and keeping the stability of the device. In this review paper, giving an update of the PSCs field, briefly, introducing the history of PSCs and then focus on the key progress of the fabrication, improving the efficiency and the stability of the large-area PSCs device.

# 2. Perovskite structure and typical PSCs structure

#### 2.1 Perovskite structure and characteristics

Perovskite was discovered in 1839, which originally referred to a kind of ceramic oxides with the general molecular formula ABX<sub>3</sub>.<sup>1</sup> Recently, PSCs absorber layer is mainly organic–inorganic perovskite layer, the general molecular formula is also ABX<sub>3</sub> (Fig. 3), where A is an organic cation (*i.e.* CH<sub>3</sub>NH<sub>3</sub><sup>+</sup>, NH<sub>2</sub>CH=NH<sub>2</sub><sup>+</sup>, CH<sub>3</sub>CH<sub>2</sub>NH<sub>3</sub><sup>+</sup>), B is metal cation (*i.e.* Pb<sup>2+</sup>, Sn<sup>2+</sup>, Ge<sup>2+</sup>) and X is halogen anion (*i.e.* F<sup>-</sup>, Cl<sup>-</sup>, Br<sup>-</sup>, I<sup>-</sup>), are the most relevant ones for PSCs.

The perovskite arrangement is approximated on its geometric tolerance factor (t),

$$t = \frac{r_{\rm A} + r_{\rm X}}{\sqrt{2}(r_{\rm B} + r_{\rm X})} \tag{1}$$

where  $r_A$ ,  $r_B$  and  $r_X$  are the efficient ionic radius for A, B and X ions, respectively. When the t = 1.0, the perovskite is a perfect cubic perovskite.<sup>50</sup> However, octahedral distortion is assessed when t < 1, which influences electronic characteristics.<sup>51</sup> For alkali metal halide perovskite, formability is anticipated for 0.813 < t < 1.107.<sup>50,51</sup> In Table 2, the  $r_A$  in APbX<sub>3</sub> (X = Cl, Br, I) perovskite has been calculated for t = 0.8 and t = 1 based on effective ionic radii.<sup>51</sup> As the tolerance of CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> (MAPbI<sub>3</sub>)

Table 1	Summary of large-ar	ea perovskite solar cells
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PSCs configuration	Cells area (cm <sup>2</sup> )	Active area (cm <sup>2</sup> )	PCE (%)	Ref.	
ITO/PEDOT:PSS/MAPbI <sub>3</sub> /PCBM/C <sub>60</sub> /BCP/Al	1	1	12.2	32	
FTO/TiO <sub>2</sub> /MAPbI <sub>3</sub> /spiro-OMeTAD/Au	1	1	11.7	33	
ITO/HTL/PFN/CH3NH3PbI3/PCBM/Al	1	1	17.04	34	
FTO/TiO <sub>2</sub> /(FAPbI <sub>3</sub> ) <sub>0.85</sub> (MAPbBr <sub>3</sub> ) <sub>0.15</sub> /spiro-OMeTAD/Au	1	1	18.32	35	
FTO/c-TiO <sub>2</sub> /me-TiO <sub>2</sub> /MAPbI <sub>3</sub> /spiro-OMeTAD/Au	1	1	19.3	36	
FTO/bl-TiO <sub>2</sub> /mp-TiO <sub>2</sub> /perovskite/spiro-OMeTAD/Au	1	1	19.6 (certified)	37	
FTO/TiO <sub>2</sub> /me-TiO <sub>2</sub> :perovskite/perovskite/PTAA/Au	1	1	19.7 (certified)	3	
ITO/SnO <sub>2</sub> /(FAPbI <sub>3</sub> ) <sub>1-x</sub> (MAPbBr <sub>3</sub> ) <sub>x</sub> /spiro-OMeTAD/Au	1	1	20.1 (certified)	38	
ITO/TiO <sub>2</sub> /CH <sub>3</sub> NH <sub>3</sub> PbI <sub>3-x</sub> Cl <sub>x</sub> /spiro-OMeTAD/Au	4	1	13.6	39	
FTO/c-TiO <sub>2</sub> /me-TiO <sub>2</sub> /perovskite/spiro-OMeTAD/Au	1.01	1.01	16.61	40	
FTO/NiMgLiO/MAPbI <sub>3</sub> /PCBM/Ti(Nb)O <sub>x</sub> /Ag	1.02	1.02	16.2 (15 certified)	41	
Anode/HEL/perovskite/gradient interlayer/ETL/cathode	1.022	1.022	18.21 (certified)	42	
FTO/c-TiO <sub>2</sub> /me-TiO <sub>2</sub> /perovskite/spiro-OMeTAD/Au	1.05	1.05	15.89	43	
FTO/ZnO/MAPbI <sub>3</sub> /spiro-OMeTAD/Au	1.10	1.10	3.08	44	
FTO/TiO <sub>2</sub> -Cl/FA <sub>0.85</sub> MA <sub>0.15</sub> PbI <sub>2.55</sub> Br <sub>0.45</sub> /spiro-OMeTAD/Au	1.10	1.10	19.5 (certified)	31	
SAM/PC <sub>61</sub> BM/MAPbI <sub>3</sub> /PTAA/Ag	1.20	1.20	15.98	45	
ITO/PEDOT:PSS/MAPbI <sub>3</sub> /PCBM/C <sub>60</sub> /BCP/Al	64.0	1.50	6.0	32	
ITO/PEDOT:PSS/(PEI) <sub>2</sub> (MA) <sub>n-1</sub> Pb <sub>n</sub> I <sub>3n+1</sub> /PCBM/LiF/Ag	2.32	2.32	8.77	46	
SAM/PC <sub>61</sub> BM/MAPbI <sub>3</sub> /PTAA/Ag	5.04	5.04	12.79	45	
FTO/c-TiO <sub>2</sub> /TiO <sub>2</sub> or MAPbI <sub>3</sub> /spiro-OMeTAD/Au	10.1	10.1	10.4	47	
FTO/c-TiO <sub>2</sub> /me-TiO <sub>2</sub> /MAPbI <sub>3</sub> /spiro-OMeTAD/Au	36.0	36.0	15.7 (12.1 certified)	36	
FTO/c-TiO <sub>2</sub> /TiO <sub>2</sub> or MAPbI <sub>3</sub> /spiro-OMeTAD/Au	100	100	4.3	47	

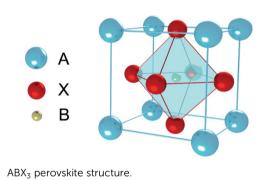


Table 2 Estimation of A cation radii in APbX<sub>3</sub>

$r_{\rm Pb}{}^a$	X <sup>a</sup>		$r_{\rm A}{}^b$ for $t = 0$	$r_{\rm A}^{\ b} {\rm fo}$	or $t =$	1.0
Pb <sup>2+</sup> (1.19 Å)	${ m Cl}^-~(r_{ m Cl}=1)$ ${ m Br}^-~(r_{ m Br}=1)$ ${ m I}^-~(r_{ m I}=2.20)$	.96 Å)	1.58 Å 1.60 Å 1.64 Å	2.43 2.50 2.59	Å	
<sup><i>a</i></sup> Effective <sup><i>b</i></sup> $r_{\rm A} = t \times \sqrt{2}$	ionic radii $\bar{k}(r_{\rm B}+r_{\rm X})-r_{\rm X}.^{50,}$		coordination	number	of	6.

is 0.83, in this manner, the deviation from a perfect cubic structure is likely to happen. $^{50,51}$ 

In the visible range, for the MAPbI<sub>3</sub>, the effective absorption coefficient is around  $1.0 \times 10^5 \text{ (mol L}^{-1})^{-1} \text{ cm}^{-1}$  at 550 nm,<sup>4,52</sup> when the thickness of perovskite films range is 500–600 nm, it can absorb complete light in films. Meanwhile, organic–inorganic perovskite exhibits better charge transfer characteristics. H. J. Snaith *et al.*<sup>5</sup> reported the diffusion lengths ( $L_D$ ) of the electrons and holes in MAPbI<sub>3</sub> and MAPbI<sub>3-x</sub>Cl<sub>x</sub>, the  $L_D$  of MAPbI<sub>3</sub> is 130 nm (electrons) and 100 nm (holes) and this of MAPbI<sub>3-x</sub>Cl<sub>x</sub> is

1100 nm (electrons) and 1200 nm (holes), respectively.<sup>5</sup> So, the organic–inorganic perovskite is an ideal absorber layer material for solar cells.

#### 2.2 Typical PSCs structure

Some of the typical structures of PSCs are shown in Fig. 4. The typical PSCs structures include the mesoporous structure (Fig. 4(a)), the planar heterojunction structure (Fig. 4(b)) and the inverted planar heterojunction structure (Fig. 4(c)). PSCs with regular configuration is transparent conductive oxide (TCO)/blocking layer (electron transport layer (ETL))/perovskite absorber layer/hole transport layer (HTL) material/gold (Au). The widely accepted a simplified operation principle of PSCs is presented as: perovskite absorber layer absorbs light and generates charges while the light on the PSCs. The electrons and holes pairs are created by the thermal energy, which diffuse and get separate through electron and hole selective contacts, respectively (Fig. 4(d)).<sup>53</sup> Once electrons and holes are present at the cathode and anode, respectively, external load can be powered by connecting a circuit through it.

TiO<sub>2</sub> is the most common ETL material, <sup>3,6,7,54</sup> meanwhile, other ETL materials have been used to attain over 10% efficiencies (*e.g.* ZnO,<sup>13,55,56</sup> SnO<sub>2</sub>, <sup>57-59</sup> PCBM, <sup>60-65</sup> LBSO, <sup>66</sup> *etc.*). Spiro-OMeTAD is the widely used HTL material, <sup>35,57,67</sup> the certified PCE of 22.1% in small cells.<sup>3</sup> Meanwhile, other HTL materials have been used to achieve over 10% efficiencies (*e.g.* PTAA, <sup>29,66,68</sup> P3HT, <sup>69-71</sup> PEDOT:PSS, <sup>60,61,72</sup> CuSCN, <sup>73,74</sup> triazine-Th-OMeTPA, <sup>75</sup> PVCz-OMeDAD, <sup>76</sup> OMeTPA-BDT, <sup>77</sup> NiO<sub>x</sub>, <sup>56,64,78,79</sup> CuGaO<sub>2</sub>, <sup>54</sup> X26, <sup>80</sup> X36, <sup>80</sup> NiMgLiO<sup>41</sup> *etc.*). Carbon materials, <sup>81-85</sup> aluminum, <sup>34,56,61,62</sup> silver, <sup>64,65,86</sup> and gold<sup>87-90</sup> have been used as electrode. <sup>53</sup> Fig. 5 shows the energy levels for some commonly used ETL materials, HTL materials and absorbers materials.

Fig. 3

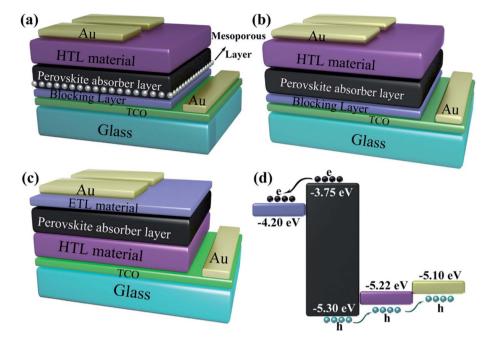


Fig. 4 Different structural configurations of PSCs, (a) mesoporous structure, (b) planar heterojunction structure, (c) inverted planar heterojunction structure and (d) schematic of electron and hole transportation.

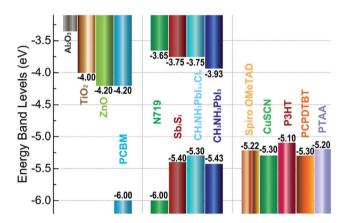


Fig. 5 Energy levels for some materials of ETL (left), absorbers (middle) and HTL (right) in solar cells.

# 3. Large-area ( $\geq 1 \text{ cm}^2$ ) perovskite films fabricating technologies

The continuous fabrication of cracks- and pinholes-free the perovskite films and the selective carrier extraction layers films is difficulty for the large-area PSCs devices. So, some researchers have reported many fabrication methods to improve the quality of the large-area perovskite films.

# 3.1 Spin-coating and vacuum flash-assisted solution process (VASP)

Spin-coating has been widely used to fabricate the large-area perovskite films.<sup>16,35,39–41,45,91</sup> The main advantage of the spin-coating method is to deposit thin films with well-defined the composition of chemical elements and the film thicknesses. Spin-coating includes one step spin-coating and two step spin-

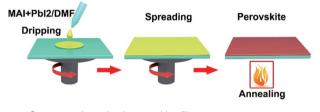


Fig. 6 One-step deposited perovskite films.

coating. One step spin-coating, briefly, methyl ammonium iodide (MAI) and lead iodide (PbI<sub>2</sub>) powders are mixed and dissolved in *N*,*N*-dimethylformamide (DMF) or dimethyl sulfoxide (DMSO), the mixed solution is spun on a TCO substrate and then annealed, attaining the perovskite films (Fig. 6). In 2015, M. Grätzel and L. Y. Han *et al.*<sup>41</sup> prepared perovskite absorber films *via* one step spin-coating, they achieved largearea PSCs with an active area 1.02 cm<sup>2</sup> that had a PCE > 15% (certified 15%). In 2016, W. Qiu and P. Heremans *et al.*<sup>39</sup> achieved large-area PSCs with 4 cm<sup>2</sup> aperture area and an active area of 1 cm<sup>2</sup>, that had a PCE of 13.6%.

Aiming at uncovered pinhole areas derive from large perovskite grains, M. J. Kim and G. H. Kim *et al.*<sup>35</sup> also developed one step spin-coating, and using high-temperature short-time annealing (HTSA) process (Fig. 7(a)), achieving the perovskite grains with sizes more than 1  $\mu$ m without pinhole (Fig. 7(d, e, h, i)). In addition, the VASP was used to fabricate perovskite film (Fig. 8(a)), the sizes of perovskite grains were between 400 and 1000 nm (Fig. 8(c)), which covered the TiO<sub>2</sub> layer.<sup>37</sup>

Two-step spin coating, briefly, MAI and PbI<sub>2</sub> powders are dissolved in DMF or DMSO, respectively.<sup>16</sup> First, the PbI<sub>2</sub> solution is spun coating on a TCO substrate and then annealing,

achieving the  $PbI_2$  films. Second, the MAI solution is spun coating on  $PbI_2$  films and then annealing, achieving the perovskite films (Fig. 9). In 2016, C. Chang *et al.*<sup>45</sup> prepared perovskite absorber films with two step spin-coating, they achieved large-area PSCs with an active area  $1.2 \text{ cm}^2$  that had a PCE of 16.2%. In 2017, E. K. Kim, J. H. Noh and S. I. Seok *et al.*<sup>3</sup> achieved large-area PSCs with an active area 1 cm<sup>2</sup> that had a certified PCE of 19.7%. In 2017, X. W. Zhang and J. B. You *et al.*<sup>38</sup> have adopted two-step spin-coating method to fabricate the (FAPbI<sub>3</sub>)<sub>1-x</sub>(MAPbBr<sub>3</sub>)<sub>x</sub> films and configure n–i–p planar structure PSCs with an active area 1 cm<sup>2</sup> that has a PCE of 20.1%.

#### 3.2 Vapor deposition

Comparing to the fabrication of the PSCs device with the spincoating technology, vapor deposition technology offers a very superior device and superior performance (Fig. 10(a)). The vapor deposition includes dual-source evaporation technology,<sup>8</sup> vapor–solid reaction,<sup>32</sup> and vapor-assisted method,<sup>50</sup> *etc.* For dual-source co-evaporation technology, it is that PbI<sub>2</sub> powders and MAI powders are made as target source, and pre-heated to 116 °C and 325 °C, respectively, which has achieved the PSCs yield an PCE of 15.4%.<sup>8</sup> This method fabricates high quality and uniformity of the perovskite films, subsequently resulting in good performance. But this method is very dependent on high

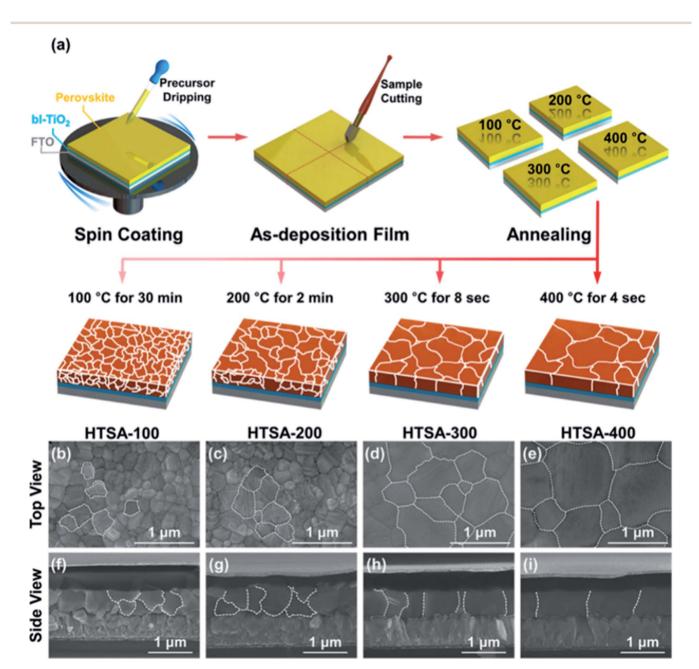
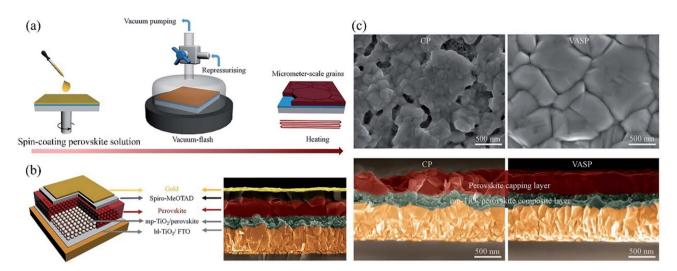
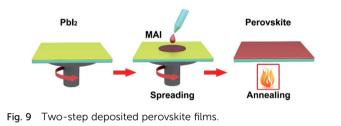


Fig. 7 (a) Schematic illustration of the annealing processes. (b-e) Surface SEM images (top view) of the perovskite films. (f-i) Their cross-sectional images (side view), respectively.<sup>35</sup>



**Fig. 8** (a) Schematic illustration of nucleation and crystallization procedures during the formation of perovskite film *via* VASP. (b) Schematic illustration of the PSCs configuration and SEM image. (c) Surface and cross-sectional SEM images of the perovskite films fabricated by the conventional process (CP) and VASP.<sup>37</sup>



temperature and high vacuum conditions. Alternate methods research in the literature<sup>32</sup> is vapor–solid reaction (VSR), depositing the perovskite film with low temperature (Fig. 10(b)). First, the PbI<sub>2</sub> film was spin-coated onto the ETL, and then baking on a 70 °C hot plate in air for 10 min. Second, MAI powders were dissolved in ethanol. Then the solution was homogeneously sprayed onto the bottom surface of the top plate that had been keeping at 80 °C. Finally, inside vacuum desiccator, two parallel hot plates (PHP) were putted together to synthesize perovskite thin films.<sup>32</sup> H. Zhou and S. Yin *et al.*<sup>32</sup> used this method to achieve the 8 × 8 cm<sup>2</sup> PSCs module, the average PCE was 6.0% with the active area of 1.5 cm<sup>2</sup>.

#### 3.3 Gas-induced method

For the organic–inorganic halide perovskites (OIHPs) materials, gas-induce formation/transformation (GIFT) reveal surprising properties, such as gas-induced phase/morphology transformation.<sup>92</sup> Z. Zhou, S. Pang, G. Cui *et al.*<sup>93</sup> reported that the discovery of CH<sub>3</sub>NH<sub>2</sub> (MA) induced phase/morphology transformation of the MAPbI<sub>3</sub>. As show in Fig. 11, MA gas is introduced at room temperature (RT), after 120 min, two MAPbI<sub>3</sub> single-crystals become liquefied (MAPbI<sub>3</sub>·*x*CH<sub>3</sub>NH<sub>2</sub>), eventually, merge into one liquid sphere.<sup>93</sup> Then MA gas is removed, after 120 min, perovskite back-conversion completed. Fig. 12(b) shows a poor quality of MAPbI<sub>3</sub> thin film (incomplete coverage, rough), then the MA gas treatment has been introduced to create smooth, uniform and full coverage MAPbI<sub>3</sub> thin films (Fig. 12(c)).<sup>93</sup>

In 2017, M. Grätzel and L. Han *et al.*<sup>36</sup> achieved  $8 \times 8 \text{ cm}^2$  perovskite films *via* GIFT, briefly, at atmospheric environment, dried CH<sub>3</sub>NH<sub>2</sub> gas (0.5 l min<sup>-1</sup>) was passed into a bottle that contained 2 mmol CH<sub>3</sub>NH<sub>3</sub>I or PbI<sub>2</sub> powders (Fig. 13). After 30 min, the CH<sub>3</sub>NH<sub>3</sub>I powders changed into transparent colorless liquid (CH<sub>3</sub>NH<sub>2</sub>I·3CH<sub>3</sub>NH<sub>2</sub>), and the PbI<sub>2</sub> powders

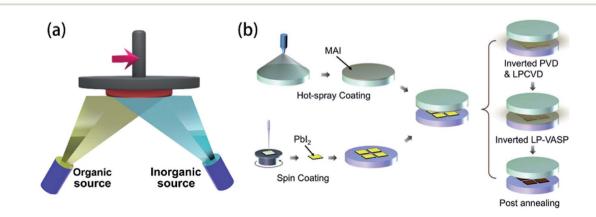


Fig. 10 (a) Schematic illustration of double source co-evaporation. (b) Schematic of vapor-solid reaction method.<sup>32</sup>

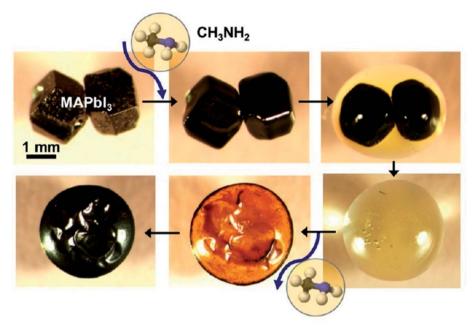


Fig. 11 In situ optical microscopy of the morphology evolution of two touching MAPbI<sub>3</sub> perovskite crystals (same magnification) upon exposure to CH<sub>3</sub>NH<sub>2</sub> gas and CH<sub>3</sub>NH<sub>2</sub> degassing.<sup>93</sup>

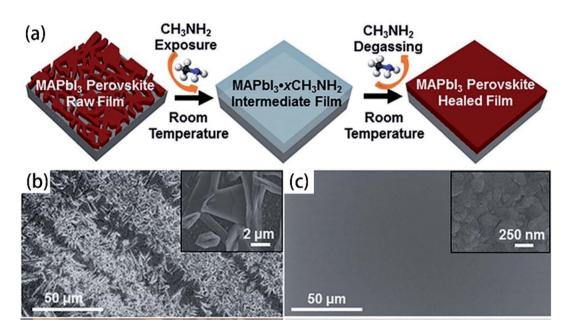


Fig. 12 (a) Schematic illustration of MA induced defect-healing of MAPbI<sub>3</sub> perovskite thin films. SEM images of MAPbI<sub>3</sub> thin films: (b) raw film and (c) healed film.<sup>93</sup>

changed into a pale-yellow paste (PbI<sub>2</sub>·CH<sub>3</sub>NH<sub>2</sub>, Fig. 13).<sup>36</sup> For the synthesis of perovskite precursor, CH<sub>3</sub>NH<sub>2</sub>I·3CH<sub>3</sub>NH<sub>2</sub> and PbI<sub>2</sub>·CH<sub>3</sub>NH<sub>2</sub> were blended stoichiometrically and ultrasonicated for 15 min (Fig. 13).<sup>36</sup> The perovskite precursor (200 µl) was dropped on a  $8 \times 8$  cm<sup>2</sup> substrate and then the precursor was covered by the polyimide (PI) film.<sup>36</sup> A pressure of 120 bar was loaded *via* a pneumatically driven squeezing board which spread the liquid precursor under the PI film. The pressure was held for 60 s and then unloaded. The thin liquid film covered with the PI film was heated at 50 °C for 2 min before peeling off the PI film. After peeling the PI film (50 mm s<sup>-1</sup>), a dense and uniform perovskite film was formed (Fig. 14(b)).<sup>36</sup> They achieved the PSCs with the device area 36 cm<sup>2</sup> (Fig. 14(c)) that had a certified PCE of 12.1%.<sup>36</sup>

#### 3.4 Other approaches

In addition, a blade coating technology is also frequently used, the schematic shows in Fig. 15.<sup>22</sup> The advantage of the blade



Fig. 13 Diagram of the CH<sub>3</sub>NH<sub>2</sub> introduced CH<sub>3</sub>NH<sub>3</sub>I and PbI<sub>2</sub> powers and the mixture of CH<sub>3</sub>NH<sub>3</sub>I·3CH<sub>3</sub>NH<sub>2</sub> and PbI<sub>2</sub>·CH<sub>3</sub>NH<sub>2</sub>.<sup>36</sup>

coating technology can control the distance between blade and the substrate, and the *in situ* thermal-treatment temperature. In 2015, S. Razza and A. D. Carlo *et al.*<sup>47</sup> used the blade coating technology, which achieved a module PSCs with a 10.1 cm<sup>2</sup> active area that had the efficiency of 10.4%.<sup>47</sup> Meanwhile, an efficiency of 4.3% had been measured for a module area of 100 cm<sup>2</sup>.<sup>47</sup> In 2016, J. L. Yang *et al.*<sup>94</sup> reported an approach to fabricate ultra-long nanowires array and highly oriented CH<sub>3</sub>-NH<sub>3</sub>PbI<sub>3</sub> thin films in ambient environments, briefly, this approach included large-scale roll-to-roll micro-gravure printing and doctor blading (Fig. 16), which produced perovskite nanowires lengths as long as 15 mm.<sup>94</sup>

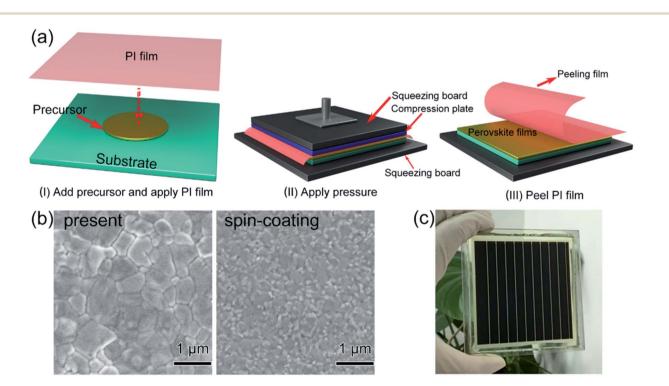


Fig. 14 Diagram of the pressure processing method for the deposition of perovskite films. (a) The steps of the pressure processing method. (b) SEM images. (c) Photograph of a perovskite module.<sup>36</sup>

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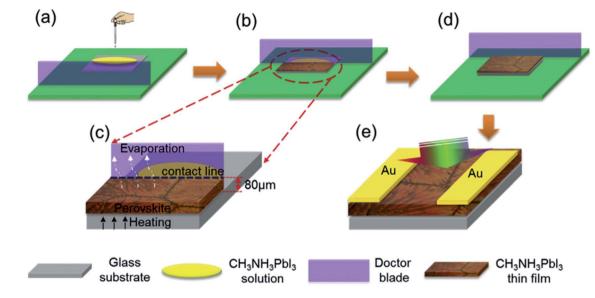


Fig. 15 Schematic representation of *in situ* doctor blading technology for fabricating CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> films.<sup>22</sup>

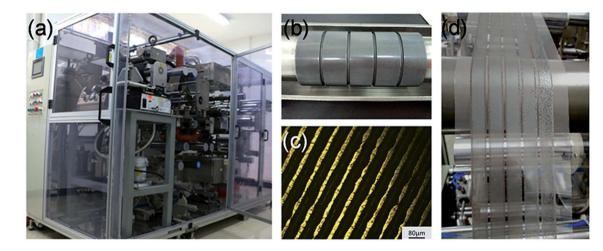


Fig. 16 (a) Photo of self-developed R2R multi-function printer. (b) Photo of micro-gravure printer roller. (c) Optical microscope image of engraved micro-gravure printer roller. (d) A photo of R2R printing process.<sup>94</sup>

# 4. Methods of improving PCE for large-area ( $\geq 1 \text{ cm}^2$ ) perovskite solar cells

For the large-area PSCs device, improving the PCE, the first method is to change the chemical composition of perovskite, adjusting its band gap and increasing the charge generation.<sup>3,29,31,35,38,46</sup> The second approach is to increase the grain size of perovskite, decreasing the cracks and pinholes, that reduces the bulk defect recombination and electric leakage, and increase  $V_{\rm oc}$ .<sup>35–38</sup> The third approach is interface modification, which reduces interface contact resistance, and reduce interface and surface recombination, and increase  $J_{\rm sc}$ .<sup>31,41,45,95</sup>

For the large-area PSCs device, with the increasing of cell size, the series resistance  $(R_s)$  increase among the charge transfer layers, the absorber layer and the electrode layers. At

the same time, the number of the crack and the pinholes increase, that from the shunt resistance  $(R_{\rm sh})$  and the value of  $R_{\rm sh}$  decrease. Incorporating these resistances into the circuit

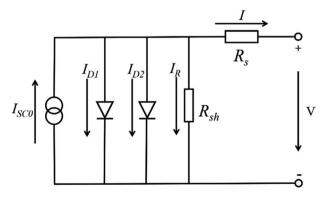
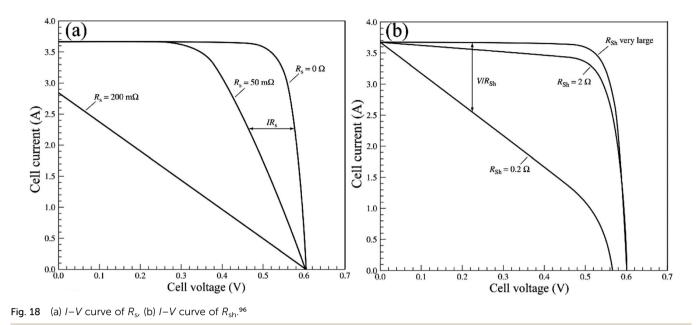


Fig. 17 Incorporating these resistances into the circuit model.96



model of the solar cells device shows in Fig. 17.<sup>96</sup> The increasing of  $R_{\rm s}$  and the decreasing of  $R_{\rm sh}$  increase the interface losses of the large-area PSCs device, that is the major reason of the lower efficiency for the large-area PSCs device.<sup>95</sup>

The current expression in the circuit can be written as eqn (2).<sup>96</sup>

$$I = I_{\rm SC0} - I_{\rm D1} \left[ e^{q(V+IR_{\rm s})/kT} - 1 \right] - I_{\rm D2} \left[ e^{q(V+IR_{\rm s})/kT} - 1 \right] - \frac{V+IR_{\rm s}}{R_{\rm sh}}$$
(2)

where  $I_{SC0}$  is the short-circuit current when there are no parasitic resistances ( $R_s$  and  $R_{sh}$ ). The effect of these parasitic resistances on the *I*-*V* characteristic is shown in Fig. 18. Form the eqn (2), the series resistance,  $R_s$  increase, has no effect on the open-circuit voltage, but reduces the short-circuit current ( $J_{sc}$ ) and fill factor (FF) (Fig. 18(a)). Conversely, the shunt resistance,  $R_{sh}$  decrease, has no effect on the short circuit current, but reduces the open-circuit voltage ( $V_{oc}$ ) and FF (Fig. 18(b)).

#### 4.1 Chemical molecular engineering

For the perovskite material, its band gap can regulate via exchange the chemical molecular or element, achieving an ideal band gap of the perovskite material. Such as, through intramolecular exchange, formamidinium (FA) molecular is frequently used to replace methylamine (MA) in MAPbI<sub>3</sub>, forming FAPbI<sub>3</sub> and adjusting the band gap. In 2015, W. S. Yang and J. H. Noh et al.<sup>29</sup> have fabricated FAPbI<sub>3</sub> films, its band gap is 1.47 eV smaller than MAPbI<sub>3</sub> (1.50 eV). Meanwhile, the PCE of FAPbI<sub>3</sub>-based PSCs is up to 20.1%. In 2017, J. Y. Kim and D. S. Kim et al.<sup>35</sup> fabricated (FAPbI<sub>3</sub>)<sub>0.85</sub>(MAPbBr<sub>3</sub>)<sub>0.15</sub> (1.55 eV) as absorber layer of the PSCs device, which had a maximum PCE exceeding 18% over a 1 cm<sup>2</sup> active area. In 2017, E. K. Kim, J. H. Noh and S. I. Seok et al.3 introduced additional iodide ions into the organic cation solution, that decreased the concentration of deeplevel defects. They fabricated of the  $(FAPbI_3)_x(MAPbBr_3)_{1-x}$ -based PSCs with a certified PCE of 19.7% in 1 cm<sup>2</sup> cells.<sup>3</sup> Adding

inorganic cesium to triple-cation perovskite compositions, E. H. Sargent *et al.*<sup>31</sup> have reported the best-performance large-area (1.1 cm<sup>2</sup>) PSCs (Cs<sub>0.05</sub>FA<sub>0.81</sub>MA<sub>0.14</sub>PbI<sub>2.55</sub>Br<sub>0.45</sub>, 1.60 eV), that has a PCE of 20.3%. In 2017, X. W. Zhang and J. B. You *et al.*<sup>38</sup> used the (FAPbI<sub>3</sub>)<sub>1-x</sub>(MAPbBr<sub>3</sub>)<sub>x</sub> (1.55 eV) as absorber layer for PSCs with the certified efficiency of 20.1% in large-area (1 cm<sup>2</sup>).<sup>38</sup>

#### 4.2 Improving preparation technology

The high quality (cracks- and pinholes-free) large-area perovskite film is precondition for the achieving high PCE of PSCs. Because the cracks and pinholes can form electric leakage (forming the  $R_{\rm sh}$ ), which lead to the decreasing the  $V_{\rm oc}$  and FF, and reduce the PCE of PSCs. So, M. J. Kim and G. H. Kim et al.35 developed one step spin-coating, and using high-temperature short-time annealing process (Fig. 7(a)), achieving the perovskite grains with sizes more than 1 µm without pinhole (HTSA-400, Fig. 7(d, e, h and i)). They fabricated PSCs device with 1 cm<sup>2</sup>, which achieved the PCE of 18.32% with HTSA-400 (Fig. 19(d)), but the PCE is only 13.82% with HTSA-100 (Fig. 19(c)).<sup>35</sup> X. Li and M. Grätzel et al.<sup>37</sup> used the vacuum flash-assisted solution processing (VASP) to fabricate perovskite film (Fig. 8(a)), the sizes of perovskite grains were between 400 and 1000 nm (Fig. 8(c)). They fabricated the PSCs device with an aperture area exceeding 1 cm<sup>2</sup>, the certified PCE of 19.6%.<sup>37</sup> In 2015, Z. Zhou, S. Pang, G. Cui et al.93 reported that the MA gas treatment has been introduced to create smooth, uniform and full coverage MAPbI<sub>3</sub> thin films (Fig. 12(c)).93 This MAPbI<sub>3</sub> was used to fabricate the PSCs device, the PCE increased from 5.7% to 15.1%, was observed, which was clearly the result of the improving film morphology.93

#### 4.3 Interface engineering

Interface engineering can optimize interface contact, mitigate carrier recombination and increase carrier collection, which is extremely important to achieve high-performance and high-

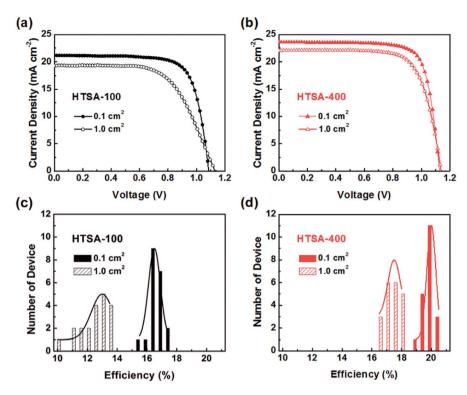


Fig. 19 (a) Current–voltage curves of perovskite solar cells derived from HTSA-100 and (b) HTSA-400 with an active area  $0.1 \text{ cm}^2$  and a  $1 \text{ cm}^2$ . (c) Histogram of PCEs derived from HTSA-100 and (d) HTSA-400 with an active area  $0.1 \text{ cm}^2$  and  $1 \text{ cm}^{2.35}$ 

stability PSCs. Interface engineering includes doped, plasma etching, self-assembled monolayers and interface buffer layer *etc.* 

Doping for the charge transport layers, that can improve their electrical performance, such as improving carrier concentration and mobility. For Li-Mg co-doped NiO films, the conductivity is  $2.32 \times 10^{-3}$  S cm<sup>-1</sup>, ~12 times greater than that of the pure Mg<sub>x</sub>Ni<sub>1-x</sub>O.<sup>41</sup> The conductivity of Nb<sup>5+</sup> doped TiO<sub>2</sub> films is  $\sim 10^4$  S cm<sup>-1</sup>,  $\sim 100$  to 1000 times greater than that of the pure TiO2.41 In 2015, M. Grätzel and L. Y. Han et al.41 have used Mg-Li co-doped NiO as HTL and Nb doped TiO<sub>x</sub> as ETL material in inverted planar PSCs to achieve very rapid carrier extraction, increasing the cell FF from 0.64 to 0.827. Meanwhile, they fabricated a large-area (>1 cm<sup>2</sup>) PSCs (Fig. 20(a)) with a certified efficiency of 15%.41 The contact-passivation can mitigate interfacial recombination and improve interface binding in lowtemperature planar PSCs. H. R. Tan and E. H. Sargent et al.<sup>31</sup> reported a contact-passivation strategy using chlorine-capped TiO<sub>2</sub> (Cl-TiO<sub>2</sub>) colloidal nanocrystal film as ETL, the chargerecombination lifetime increased from 64 µs to 145 µs compare with pure TiO<sub>2</sub> film.<sup>31</sup> They fabricated the planar PSCs for active areas of 1.1 cm<sup>2</sup>, that achieved a certified efficiency of 19.5% without hysteresis.31 Interlayers are thin layers or monolayers of organic molecules that modify a specific interface in the solar cell.97 In 2016, C.Y. Chang and Y. C. Chang et al.45 reported an approach for the modification of interface layer via introducing thiol-functionalized self-assembled monolayers (SAMs, Fig. 21(b)), which decreased interface charge recombination and increased the value of  $J_{\rm sc}$  (19.43 mA cm<sup>-2</sup> to

21.68 mA cm<sup>-2</sup>) and FF (0.67 to 0.72). They fabricated a large-area (1.2 cm<sup>2</sup>) PSCs with the PCE up to 15.98%.<sup>45</sup> Y. Wu and X. Yang *et al.*<sup>42</sup> reported a perovskite–fullerene graded heterojunction structure, which improved the photoelectron collection and reduced recombination loss. They fabricated the PSCs of 1.022 cm<sup>2</sup>, that had a certified PCE of 18.21%.<sup>42</sup>

# 5. Stability of large-area ( $\geq 1 \text{ cm}^2$ ) perovskite solar cells

In recent years, the certificated PCE of the large-area (1 cm<sup>2</sup>) PSCs has achieved 20.1%.<sup>38</sup> However, the major issue of largearea PSCs for commercial applications is the poor long-term device stability. For the stability of the perovskite materials and devices, it is necessary to consider the effects of temperature, illumination and ambient (oxygen, moisture) exposure. Many papers have reported about this important issue.<sup>1,51,53,97-107</sup>

#### 5.1 Degradation mechanisms

The degradation of the PSCs device includes the degradation of the active layer, the degradation of charge transport layers, and the degradation of electrodes.<sup>104</sup> The MAPI<sub>3</sub> films are frequently used as absorber layer film. But the major problem with MAPbI<sub>3</sub> is that has thermal decomposition (exceeding 85 °C)<sup>108,109</sup> and water decomposition.<sup>1,48,110</sup> Some researchers have reported the decomposition process of MAPbI<sub>3</sub>. B. Philippe and H. Rensmo *et al.*<sup>109</sup> exposed the MAPbI<sub>3</sub> and MAPbI<sub>3-x</sub>Cl<sub>x</sub> to various environments. From the photoelectron spectroscopy results with

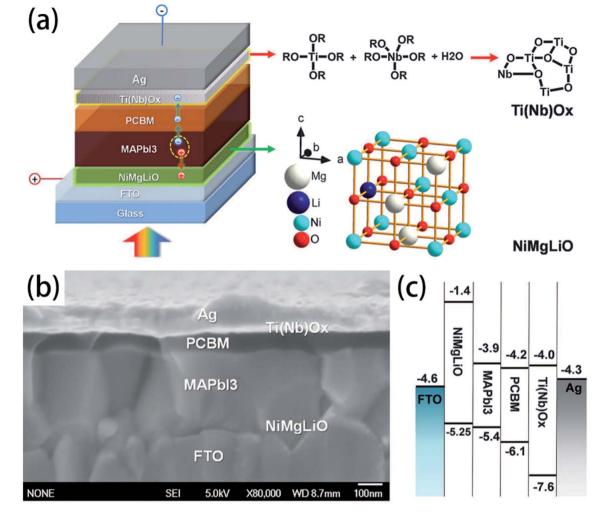


Fig. 20 Structure and band alignments of the PSCs, (a) diagram of the cell configuration highlighting the doped charge carrier extraction layers. (b) A high-resolution cross-sectional SEM image of a complete solar cell. (c) Band alignments of the solar cell.<sup>41</sup>

the different environments, the perovskite has decomposed into PbI<sub>2</sub>, but this degradation seems to occur already at 100 °C and is not only related to large humidity (Fig. 22(a)). Meanwhile, they observed a slow degradation occurs even when stored in an inert atmosphere such as argon.<sup>109</sup> L. D. Wang et al.<sup>48</sup> verified that oxygen, together with moisture, could lead to the irreversible degradation of MAPbI<sub>3</sub>. They exposed TiO<sub>2</sub>/CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> film to air with a humidity of 60% at 35 °C for 18 h, and then, the absorption between 530 and 800 nm greatly decreased (Fig. 22(b)), the MAPbI<sub>3</sub> decomposed into PbI<sub>2</sub> and I<sub>2</sub> (Fig. 21(c)).48 The degradation mechanism of MAPbI<sub>3</sub> upon exposure to moisture in absence of illumination involves the formation of hydrate form, which can be reversible.<sup>11,48,111,112</sup> However, continuing exposure to moisture and/or exposure to illumination leads to the irreversible degradation to PbI2.111 For ETL material, TiO<sub>2</sub> is especially sensitive to ultraviolet light, in the ultraviolet light, Ti<sup>4+</sup> adsorb O<sub>2</sub> and convert into Ti<sup>3+</sup>, increasing the charge recombination.<sup>113</sup> Meanwhile, the lithium salt in spiro-MeOTAD is easy to absorb moisture and decrease the PSCs device stability.

#### 5.2 Methods of improving stability

In recent years, many methods have been researched to improve the PSCs device stability. Due to the poor stability of MAPI<sub>3</sub>, the first method is to modify the chemical constituents or structure of the perovskite. For example, 2D perovskites, compared with 3D perovskites, 2D perovskites have the higher carrier mobility while maintaining good ambient stability.114,115 The 2D Ruddlesden-Popper layered perovskites ((BA)2(MA)2Pb3I10 and  $(BA)_2(MA)_3Pb_4I_{13})$  have been studied (Fig. 23(a)).<sup>115</sup> The (BA)<sub>2</sub>(MA)<sub>3</sub>Pb<sub>4</sub>I<sub>13</sub> film color gets darker with increasing temperature (Fig. 23(b)).115 H. Tsai and W. Nie et al.115 have achieved a PCE of 12.51% with 2D (BA)2(MA)3Pb4I13 PSCs device. Under the constant light illumination, after 2500 h, the 2D perovskite devices is retaining 70% of its original PCE without encapsulated and 98% with encapsulated. The 3D perovskite devices have degraded < 10% of its original PCE after 2500 h (Fig. 24(a and c)). Fig. 24(b) shows the PCE of the unencapsulated 2D and 3D devices, that shows degradation after 60 h, under 65% relative humidity.<sup>115</sup> With simple encapsulation, after 2500 h, the 2D devices retained 80% of its original PCE under 65% relative humidity, but the 3D devices had

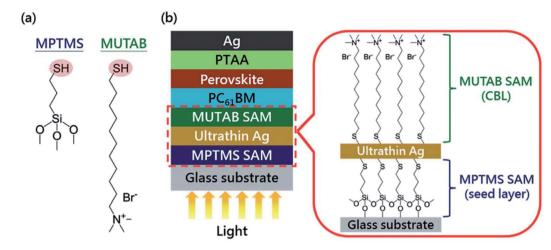


Fig. 21 (a) Chemical structures of SAM molecules. (b) Schematic illustration of the device architecture used in this study.45

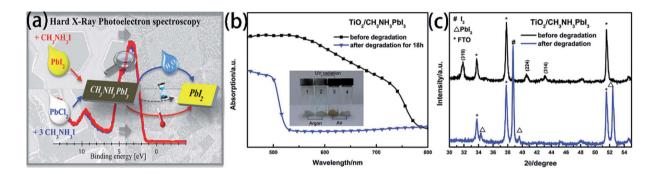


Fig. 22 (a) Degradation of MAPbI<sub>3</sub> in moisture and air atmosphere.<sup>109</sup> (b) UV-vis absorption spectra of TiO<sub>2</sub>/MAPbI<sub>3</sub> film before and after degradation.<sup>48</sup> (c) XRD patterns of TiO<sub>2</sub>/MAPbI<sub>3</sub> film before and after degradation.<sup>48</sup>

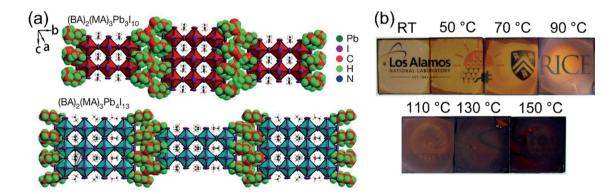


Fig. 23 Crystal structure and thin-film characterization of layered perovskites. (a) The crystal structure of the Ruddlesden–Popper  $(BA)_2(MA)_2Pb_3|_{10}$  and  $(BA)_2(MA)_3Pb_4|_{13}$  layered perovskites. (b) Photos of  $(BA)_2(MA)_3Pb_4|_{13}$  thin films cast from room temperature (RT) to 150 °C.<sup>115</sup>

been degraded (Fig. 24(d)).<sup>115</sup> K. Yao *et al.*<sup>46</sup> used the polyethylenimine (PEI) cations to fabricate the 2D perovskite compounds (PEI)<sub>2</sub>(MA)<sub>*n*-1</sub>Pb<sub>*n*</sub>I<sub>3*n*+1</sub> (*n* = 3, 5, 7), which was used as absorber layer to fabricate PSCs with an aperture area of 2.32 cm<sup>2</sup> under ambient humidity that have a PCE up to 8.77%. After 500 h, the PCE of the 2D large-area PSCs device only decreased by ~5%.<sup>46</sup> Furthermore, the alkali metal cation is introduced into the perovskite material, which can improve the stability of the PSCs device.<sup>31,68,116</sup> E. H. Sargent *et al.*<sup>31</sup> added cesium cation to fabricate a triple-cation perovskite compositions films ( $Cs_{0.05}$ - $FA_{0.81}MA_{0.14}PbI_{2.55}Br_{0.45}$ ), that was made the large-area (1.1 cm<sup>2</sup>) PSCs with a PCE up to 20.3% (Fig. 25(b and c)). After 90 days, the PSCs devices retained 96% of its initial PCE (Fig. 25(a)).<sup>31</sup> Rubidium (Rb) cations can stabilize the black

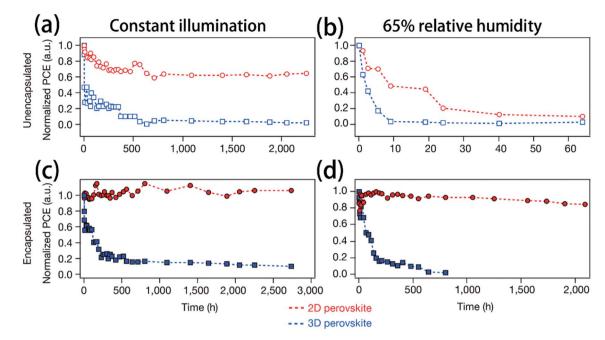
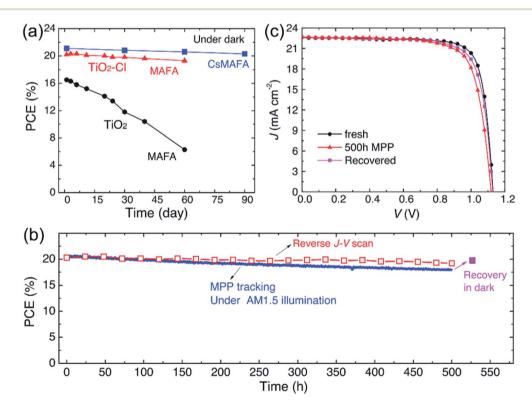


Fig. 24 (a and c) Photostability tests under constant AM1.5G illumination for 2D ( $(BA)_2(MA)_3Pb_4|_{13}$ ; red) and 3D (MAPbl<sub>3</sub>; blue) perovskite devices. (b and d) Humidity stability tests under 65% relative humidity at in a humidity chamber for 2D ( $(BA)_2(MA)_3Pb4|_{13}$ ; red) and 3D (MAPbl<sub>3</sub>; blue) perovskite devices.<sup>115</sup>

phase of FA perovskite and be integrated into PSCs, M. Saliba and M. Grätzel *et al.*<sup>116</sup> have used RbCsMAFAPbI<sub>3</sub> as absorber layer of the PSCs device. After 500 h at 85  $^{\circ}$ C under continuous

illumination, the device has retained 95% of its initial PCE (Fig. 26(d)).<sup>116</sup>



**Fig. 25** Long-term device stability of PSCs with  $TiO_2$ –Cl and  $TiO_2$ . (a) Dark storage stability of non-encapsulated PSCs. (b) Continuous maximum power point tracking for 500 hours of a high performance unsealed CsMAFA cell with  $TiO_2$ –Cl in nitrogen atmosphere under constant simulated solar illumination. (c) *J*–*V* curves of the PSCs (CsMAFA) from (b) at various stages.<sup>31</sup>

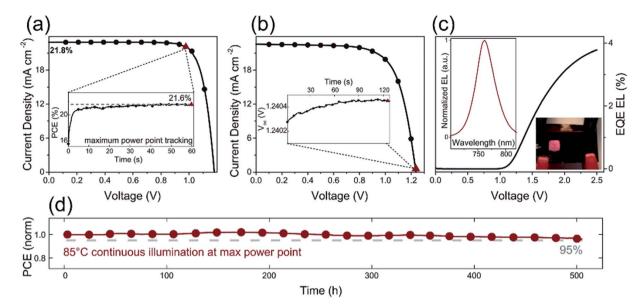
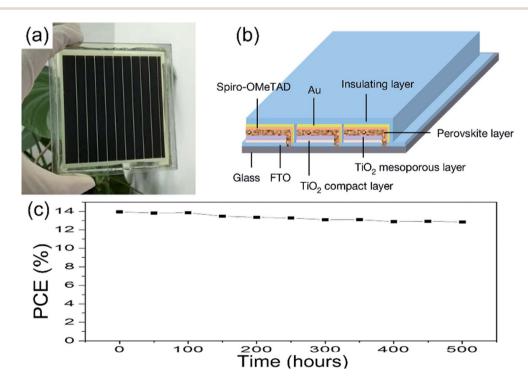


Fig. 26 (a) J-V curve of RbCsMAFA solar cell. (b) J-V curve of the highest- $V_{oc}$  device. (c) EQE electroluminescence (EL) as a function of voltage. (d) Thermal stability test of a perovskite solar cell.<sup>116</sup>

The second method for improving the PSCs device stability is to modify the charge transport layer (ETL and HTL), or use the new type charge transport material.<sup>61</sup> Because TiO<sub>2</sub> is especially sensitive to ultraviolet light,<sup>113</sup> some new ETL materials have been reported. A. D. Carlo *et al.*<sup>117</sup> reported an additional lithium-neutralized graphene oxide (GO-Li) layer as interface layer was inserted between TiO<sub>2</sub> ETL and perovskite layer, that improved the stability of PSCs devices.<sup>117</sup> A. Hagfeldt *et al.*<sup>118</sup> has used ZnO nanorod arrays as ETL replace the TiO<sub>2</sub>, achieving the PSCs device, it has been exposed in atmospheric environment without encapsulation, and maintaining 90% of the original efficiency. X. W. Zhang and J. B. You *et al.*<sup>57</sup> have used SnO<sub>2</sub> as ETL for planar-structure PSCs, it is found that the devices can maintain almost their original efficiency when store in dry air conditions for 40 days.<sup>57</sup> J. H. Noh and S. I. Seok *et al.*<sup>66</sup> used Ladoped BaSnO<sub>3</sub> as ETL, the PSCs retained 93.3% of its initial PCE



**Fig. 27** Illustration of the perovskite module and device performance. (a) Photograph of a module. (b) Diagram of the module structure. (c) Evolution of the photovoltaic stability of an encapsulated perovskite solar module.<sup>36</sup>

after 1000 hours, whereas the  $TiO_2$  cells had completely degraded within 500 hours.

For the HTL materials, spiro-OMeTAD is the most commonly used HTL material.35,57,67 the certified PCE of 22.1% in small cell.3 But the lithium salt in spiro-MeOTAD is easy to absorb moisture and reduce the PSCs device stability. So inorganic and hydrophobic hole transport material are used to improve the PSCs device stability.<sup>41,54,74,78,79</sup> M. Grätzel and L. Y. Han et al.<sup>41</sup> used Li<sub>0.05</sub>Mg<sub>0.15</sub>Ni<sub>0.8</sub>O as HTL material and Ti(Nb)O<sub>x</sub> as ETL to fabricate inverted planar heterojunction structure device (p-in), under simulated solar light, the PSCs device maintained 90% of the original efficiency after 1000 h. S. H. Yang et al.79 has fabricated inverted planar heterojunction structure for NiObased PSCs device (p-i-n), achieving more than 85% of its original PCE has been kept after 150 days. Z. B. He et al.78 used NiO<sub>x</sub> nanocrystal as HTL in planar PSCs device. After 1000 h, the PCE of PSCs device maintained 87% of its initial value. N. Arora and M. Grätzel et al.74 used one new HTL material CuSCN. They achieved the PSCs with PCE > 20%, after 1000 hours at 60 °C, the PSCs devices retained >95% of their initial efficiency. CuGaO<sub>2</sub> as HTL in n-i-p configuration PSCs, exposing it directly to the ambient environment without encapsulation. After 30 days, it maintains 87% its initial PCE.54

Other methods for improving the PSCs device stability include the PSCs structure optimization, interface optimization, encapsulation, *etc.*<sup>81,82,119</sup> A hole-conductor-free structure of the PSCs can achieve long-term stability. Exposing the PSCs device (c-TiO<sub>2</sub>/m-TiO<sub>2</sub>/ZrO<sub>2</sub>/carbon) under full AM 1.5 simulated sunlight over 1008 hours, the PCE maintains 100% of its initial value.<sup>82</sup> To improve the stability of the device, the insulation material encapsulate the PSCs device is frequently used. M. Grätzel and L. Y. Han *et al.*<sup>36</sup> encapsulated the largearea PSCs device (36.1 cm<sup>2</sup>, TiO<sub>2</sub> ETL, Fig. 27(a and b)) by the insulation material, the module retained 90% of its initial performance after 500 h (Fig. 27(c)).

#### 6. Other issues

#### 6.1 Cost analysis

For conventional solar PV technology, it need high energy and vacuum to process solar cells. Thus, these PSCs can turn-out to be a promising solution in replacing the conventional PV technology. In this section, we briefly analyze the cost for various raw materials of a 1 m<sup>2</sup> PSCs module. Conventional PSCs device architecture is shown in Fig. 4(a), that include glass substrate, TCO (FTO), ETL (TiO<sub>2</sub>), perovskite absorber layer (MAPbI<sub>3</sub>), HTL (spiro-OMeTAD) and metal electrode (Au). For 1 m<sup>2</sup> conventional PSCs module, raw material utilization for cleaning, deposition of various layers and encapsulation of the module were extracted from various available literature sources and their corresponding data are included in Table 3.120,121 From the data (Table 3), it is clear that about 43% of the total raw material cost is from FTO substrate, about 34% from the HTL material (spiro-OMeTAD), and 18% from metal electrode (Au).120,121

These data suggest the need for replacement of conventional FTO substrate, HTL material and Au electrode. The efficiency of

Table 3 Cost breakdown of raw materials utilized in fabricating a PSC module of  $1 \text{ m}^2$  with 70% active area<sup>120,121</sup>

Raw material	Qty	Price (in USD)	Contribution towards total cost (%)	Comments
FTO glass Ethanol DI water	1 m <sup>2</sup> 32.84 ml 32.70 ml		43.0500	Processing cost of FTO is included
HCL solution	4.66 ml	1.8204		
Blocking layer				
TAA	19.16 ml	7.339	0.0066	For 100 nm layer
Ethanol	32.84 ml	4.59		and post deposition
DI water	32.70 ml	0.002		cleaning is included
ETL material				
TiO <sub>2</sub>	49.5 g	41.12	0.02291	For 250 nm thick layer
Perovskite layer				
PbI <sub>2</sub>	1.38 g	4.26	0.003811	For 100 nm thick
DMF	2.98 ml	0.5502		solvent PbI <sub>2</sub> followed
MAI	0.143 g	0.49		by 200 nm thick
IPA	14.29 ml	1.538		solvent MAI
HTL material				
Spiro-OMeTAD	0.850 g	603.65	33.973	For 200 nm thick
Chlorobenzene	10.67 ml	5.9		solvent HTM layer
Cathode				
Au	1.65 g	330	18.392	For 100 nm thick layer
Encapsulation				
3 M tape		22.32	0.012	Taped on
PET	61.7 g	0.03		both sides

the PSCs device on ITO-free analogues achieved 11%.<sup>122</sup> Some new and cheap HTL materials have been reported, such as NiO (PCE ~ 18.47%),<sup>79</sup> triazine-Th-OMeTPA (PCE ~ 12.51%),<sup>75</sup> CuGaO<sub>2</sub> (PCE ~ 18.51%),<sup>54</sup> CuSCN (PCE ~ 20.4%),<sup>74</sup> NiMgLiO (PCE ~ 16.2%),<sup>41</sup> etc. Meanwhile, the efficiency for carbon based HTM-free PSCs devices achieved 15.9%.<sup>81</sup> Although, the PCE of spiro-OMeTAD-free PSCs device is little lower than the conventional PSCs, with small sacrifice in efficiency, low-cost and highly stable carbon based HTM-free PSCs can be fabricated.

#### 6.2 Environmental issues - the presence of lead

Environmental issues are a well-recognized issue for PSCs.<sup>104,123</sup> Like CdTe, a toxic heavy metal exists in the PSCs devices. But, the CdTe is very chemically stable, organolead halide perovskites are not stable and upon ambient exposure they can degrade into products that are readily leached into the environment.<sup>104,123</sup> In the life cycle assessments (LCA), the hazards of Pb for environmental impacts exist in all stages, which include raw material extraction, synthesis of starting products, fabrication, use and decommissioning.<sup>120</sup> Thus, ideally PSCs should be subject to even more stringent safety standards and any commercial products should have clear plans for end-of-life disposal and/or recycling.<sup>104,123</sup>

To address the concerns about lead, lead-free perovskite materials have attracted the attention of many researchers, which include tin-based perovskite materials and other perovskites materials (lead-free and tin-free perovskites, such as  $MA_2CuCl_xBr_{4-x}$ ,<sup>124</sup> CsGeI<sub>3</sub>, MAGeI<sub>3</sub>, and FAGeI<sub>3</sub>,<sup>125</sup> A<sub>3</sub>Sb<sub>2</sub>I<sub>9</sub> (A = Cs, Rb),<sup>126</sup> Cs<sub>2</sub>BiAgCl<sub>6</sub>,<sup>127</sup> (*N*-methylpyrrolidinium)<sub>3</sub>Sb<sub>2</sub>Br<sub>9</sub>,<sup>128</sup> *etc.*). But, compare with lead-based perovskites, the efficiencies of tin-based PSCs commonly well below 10%,<sup>129,130</sup> the PCE values for other perovskites have been below 1%.<sup>124-126</sup>

Thus, improving encapsulation technologies, it could limit the Pb leakage during the cell operation. Researching the leadfree perovskite materials, achieving high performance lead-free PSCs device, which could to replace the lead-based PSCs device.

### 7. Conclusions

In this article, we briefly summarized the studies on large-area PSCs in recent years. Progress has been made in manufacturing larger area cells as well as modules, which is the interesting for commercialization of the technology. Approaches for fabricating the lager-area perovskite film layer are described such as spin-coating, vapor deposition, gas-induced and blade coating *etc.* It is demonstrated that these processes are useful to realize more uniform perovskite layer with larger grain sized and better surface coverage, which strongly affect consequent photovoltaic performance of devices.

Going forward, PSCs will have to reduce non-radiative recombination and improve charge transport in order to achieve the highest possible Voc values and fill factors. For the largearea PSCs device, improving the PCE, the first method is to change the chemical composition of perovskite, adjusting its band gap and increasing the charge generation. The second approach is to increase the grain size of perovskite, decreasing the cracks and pinholes, that reduces the bulk defect recombination and electric leakage, and increase  $V_{oc}$ . The third approach is interface modification, which reduces interface contact resistance, and reduce interface and surface recombination, and increase  $J_{sc}$ . Meanwhile, one key issue of the largearea PSCs is the long-term poor stability. To the improving of the stability of PSCs, which requires interdisciplinary research to find new stable materials, the choice of electrodes, barrier layers, charge transport layers and encapsulation strategies. Undoubtedly, in the near future, halide perovskite materials have emerged as an attractive alternative to conventional silicon solar cells.

## Conflicts of interest

The authors declare that there is no conflict of interests regarding the publication of this paper.

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## References

- 1 H. Tang, S. He and C. Peng, Nanoscale Res. Lett., 2017, 12, 410.
- 2 M. K. Nazeeruddin, Nature, 2016, 538, 463-464.
- 3 W. S. Yang, B. W. Park, E. H. Jung, N. J. Jeon, Y. C. Kim, D. U. Lee, S. S. Shin, J. Seo, E. K. Kim, J. H. Noh and S. I. Seok, *Science*, 2017, **356**, 1376.
- 4 S. De Wolf, J. Holovsky, S. J. Moon, P. Loper, B. Niesen, M. Ledinsky, F. J. Haug, J. H. Yum and C. Ballif, *J. Phys. Chem. Lett.*, 2014, 5, 1035–1039.
- 5 S. D. Stranks, G. E. Eperon, G. Grancini, C. Menelaou, M. J. Alcocer, T. Leijtens, L. M. Herz, A. Petrozza and H. J. Snaith, *Science*, 2013, 342, 341.
- 6 A. Kojima, K. Teshima, Y. Shirai and T. Miyasaka, J. Am. Chem. Soc., 2009, **131**, 6050.
- 7 L. Etgar, P. Gao, Z. Xue, Q. Peng, A. K. Chandiran, B. Liu, M. K. Nazeeruddin and M. Grätzel, *J. Am. Chem. Soc.*, 2012, **134**, 17396–17399.
- 8 M. Liu, M. B. Johnston and H. J. Snaith, *Nature*, 2013, **501**, 395–398.
- 9 H. J. Snaith, J. Phys. Chem. Lett., 2013, 4, 3623-3630.
- 10 Y. Ogomi, A. Morita, S. Tsukamoto, T. Saitho, N. Fujikawa, Q. Shen, T. Toyoda, K. Yoshino, S. S. Pandey, T. Ma and S. Hayase, *J. Phys. Chem. Lett.*, 2014, 5, 1004–1011.
- 11 J. Yang, B. D. Siempelkamp, D. Liu and T. L. Kelly, ACS Nano, 2015, 9, 1955–1963.
- 12 W. Ke, G. Fang, Q. Liu, L. Xiong, P. Qin, H. Tao, J. Wang, H. Lei, B. Li, J. Wan, G. Yang and Y. Yan, *J. Am. Chem. Soc.*, 2015, 137, 6730–6733.
- 13 Z. L. Tseng, C. H. Chiang and C. G. Wu, *Sci. Rep.*, 2015, 5, 13211.
- 14 M. Wang, C. Shi, J. Zhang, N. Wu and C. Ying, *J. Solid State Chem.*, 2015, **231**, 20–24.
- 15 C. Zuo and L. Ding, J. Mater. Chem. A, 2015, 3, 9063-9066.
- 16 C.-Y. Chang, W.-K. Huang, Y.-C. Chang, K.-T. Lee and C.-T. Chen, *J. Mater. Chem. A*, 2016, 4, 640–648.
- 17 F. Bella, G. Griffini, J. P. Correa-Baena, G. Saracco, M. Grätzel, A. Hagfeldt, S. Turri and C. Gerbaldi, *Science*, 2016, **354**, 203.
- 18 B. Abdollahi Nejand, P. Nazari, S. Gharibzadeh, V. Ahmadi and A. Moshaii, *Chem. Commun.*, 2017, **53**, 747–750.
- K. A. Bush, A. F. Palmstrom, Z. J. Yu, M. Boccard, R. Cheacharoen, J. P. Mailoa, D. P. McMeekin, R. L. Z. Hoye, C. D. Bailie, T. Leijtens, I. M. Peters, M. C. Minichetti, N. Rolston, R. Prasanna, S. Sofia, D. Harwood, W. Ma, F. Moghadam, H. J. Snaith, T. Buonassisi, Z. C. Holman, S. F. Bent and M. D. McGehee, *Nat. Energy*, 2017, 2, 17009.
- 20 D. Dong, H. Deng, C. Hu, H. Song, K. Qiao, X. Yang, J. Zhang, F. Cai, J. Tang and H. Song, *Nanoscale*, 2017, 9, 1567–1574.
- 21 H. Deng, X. Yang, D. Dong, B. Li, D. Yang, S. Yuan, K. Qiao, Y. B. Cheng, J. Tang and H. Song, *Nano Lett.*, 2015, **15**, 7963– 7969.
- 22 S. Tong, H. Wu, C. Zhang, S. Li, C. Wang, J. Shen, S. Xiao, J. He, J. Yang, J. Sun and Y. Gao, *Org. Electron.*, 2017, 49, 347–354.

- 23 X. L. Yang, X. W. Zhang, J. X. Deng, Z. M. Chu, Q. Jiang,
  J. H. Meng, P. Y. Wang, L. Q. Zhang, Z. G. Yin and
  J. B. You, *Nat. Commun.*, 2018, 9, 570.
- 24 H. Wu, S. H. Xu, H. B. Shao, L. Li, Y. P. Cui and C. L. Wang, *Nanoscale*, 2017, **9**, 16858–16863.
- 25 S. J. Kim, J. Byun, T. Jeon, H. M. Jin, H. R. Hong and S. O. Kim, ACS Appl. Mater. Interfaces, 2018, 10, 2490–2495.
- 26 W. Zou, R. Z. Li, S. T. Zhang, Y. L. Liu, N. N. Wang, Y. Cao, Y. F. Miao, M. M. Xu, Q. Guo, D. W. Di, L. Zhang, C. Yi, F. Gao, R. H. Friend, J. P. Wang and W. Huang, *Nat. Commun.*, 2018, 9, 608.
- 27 H. S. Kim, C. R. Lee, J. H. Im, K. B. Lee, T. Moehl, A. Marchioro, S. J. Moon, R. Humphry-Baker, J. H. Yum, J. E. Moser, M. Grätzel and N. G. Park, *Sci. Rep.*, 2012, 2, 591.
- 28 H. Zhou, Q. Chen, G. Li, S. Luo, T. B. Song, H. S. Duan, Z. Hong, J. You, Y. Liu and Y. Yang, *Science*, 2014, 345, 542–546.
- 29 W. S. Yang, J. H. Noh, N. J. Jeon, Y. C. Kim, S. Ryu, J. Seo and S. I. Seok, *Science*, 2015, 348, 1234.
- 30 O. Ergen, S. M. Gilbert, T. Pham, S. J. Turner, M. T. Z. Tan, M. A. Worsley and A. Zettl, *Nat. Mater.*, 2017, 16, 522–525.
- 31 H. Tan, A. Jain, O. Voznyy, X. Lan, F. P. Garcia de Arquer, J. Z. Fan, R. Quintero-Bermudez, M. Yuan, B. Zhang, Y. Zhao, F. Fan, P. Li, L. N. Quan, Y. Zhao, Z. H. Lu, Z. Yang, S. Hoogland and E. H. Sargent, *Science*, 2017, 355, 722–726.
- 32 X. Chen, H. Cao, H. Yu, H. Zhu, H. Zhou, L. Yang and S. Yin, J. Mater. Chem. A, 2016, 4, 9124–9132.
- 33 L.-L. Gao, C.-X. Li, C.-J. Li and G.-J. Yang, J. Mater. Chem. A, 2017, 5, 1548–1557.
- 34 J. Lee, H. Kang, G. Kim, H. Back, J. Kim, S. Hong, B. Park,
   E. Lee and K. Lee, *Adv. Mater.*, 2017, 29, 1606363.
- 35 M. Kim, G. H. Kim, K. S. Oh, Y. Jo, H. Yoon, K. H. Kim, H. Lee, J. Y. Kim and D. S. Kim, *ACS Nano*, 2017, **11**, 6057–6064.
- 36 H. Chen, F. Ye, W. Tang, J. He, M. Yin, Y. Wang, F. Xie, E. Bi, X. Yang, M. Grätzel and L. Han, *Nature*, 2017, 550, 92–95.
- 37 X. Li, D. Bi, C. Yi, J. D. Décoppet, J. Luo, S. M. Zakeeruddin, A. Hagfeldt and M. Grätzel, *Science*, 2016, 353, 58.
- 38 Q. Jiang, Z. Chu, P. Wang, X. Yang, H. Liu, Y. Wang, Z. Yin, J. Wu, X. Zhang and J. You, *Adv. Mater.*, 2017, 29, 1703852.
- 39 W. Qiu, T. Merckx, M. Jaysankar, C. Masse de la Huerta, L. Rakocevic, W. Zhang, U. W. Paetzold, R. Gehlhaar, L. Froyen, J. Poortmans, D. Cheyns, H. J. Snaith and P. Heremans, *Energy Environ. Sci.*, 2016, 9, 484–489.
- 40 Y. Tu, J. Wu, X. He, P. Guo, T. Wu, H. Luo, Q. Liu, Q. Wu, J. Lin, M. Huang, Z. Lan and S. Li, *J. Mater. Chem. A*, 2017, 5, 21161–21168.
- 41 W. Chen, Y. Wu, Y. Yue, J. Liu, W. Zhang, X. Yang, H. Chen,
  E. Bi, I. Ashraful, M. Grätzel and L. Y. Han, *Science*, 2015,
  350, 944–948.
- 42 Y. Wu, X. Yang, W. Chen, Y. Yue, M. Cai, F. Xie, E. Bi, A. Islam and L. Han, *Nat. Energy*, 2016, **1**, 16148.
- 43 S. Cacovich, L. Cina, F. Matteocci, G. Divitini, P. A. Midgley,
   A. Di Carlo and C. Ducati, *Nanoscale*, 2017, 9, 4700–4706.
- 44 Y. He, Y. Lei, X. Yang, K. Lu, S. Liu, L. Gu and Z. Zheng, *Appl. Surf. Sci.*, 2016, **389**, 540–546.

- 45 C.-Y. Chang, Y.-C. Chang, W.-K. Huang, W.-C. Liao, H. Wang, C. Yeh, B.-C. Tsai, Y.-C. Huang and C.-S. Tsao, *J. Mater. Chem. A*, 2016, 4, 7903–7913.
- 46 K. Yao, X. Wang, Y.-x. Xu, F. Li and L. Zhou, *Chem. Mater.*, 2016, **28**, 3131–3138.
- 47 S. Razza, F. Di Giacomo, F. Matteocci, L. Cinà, A. L. Palma, S. Casaluci, P. Cameron, A. D'Epifanio, S. Licoccia, A. Reale, T. M. Brown and A. Di Carlo, *J. Power Sources*, 2015, 277, 286–291.
- 48 G. Niu, X. Guo and L. Wang, J. Mater. Chem. A, 2015, 3, 8970–8980.
- 49 J. P. Correa-Baena, M. Saliba, T. Buonassisi, M. Grätzel, A. Abate, W. Tress and A. Hagfeldt, *Science*, 2017, **358**, 739–744.
- 50 M. K. Assadi, S. Bakhoda, R. Saidur and H. Hanaei, *Renewable Sustainable Energy Rev.*, 2017, **81**, 2812–2822.
- 51 N.-G. Park, Mater. Today, 2015, 18, 65-72.
- 52 H. S. Kim, J. W. Lee, N. Yantara, P. P. Boix, S. A. Kulkarni, S. Mhaisalkar, M. Grätzel and N. G. Park, *Nano Lett.*, 2013, **13**, 2412–2417.
- 53 M. I. Asghar, J. Zhang, H. Wang and P. D. Lund, *Renewable Sustainable Energy Rev.*, 2017, 77, 131–146.
- 54 H. Zhang, H. Wang, W. Chen and A. K. Jen, *Adv. Mater.*, 2017, **29**, 1604984.
- 55 M. M. Tavakoli, R. Tavakoli, Z. Nourbakhsh, A. Waleed, U. S. Virk and Z. Fan, *Adv. Mater. Interfaces*, 2016, 3, 1500790.
- 56 J. You, L. Meng, T. B. Song, T. F. Guo, Y. M. Yang, W. H. Chang, Z. Hong, H. Chen, H. Zhou, Q. Chen, Y. Liu, N. De Marco and Y. Yang, *Nat. Nanotechnol.*, 2016, **11**, 75–81.
- 57 Q. Jiang, L. Zhang, H. Wang, X. Yang, J. Meng, H. Liu, Z. Yin, J. Wu, X. Zhang and J. You, *Nat. Energy*, 2016, 2, 16177.
- 58 Z. Liu, J. Hu, H. Jiao, L. Li, G. Zheng, Y. Chen, Y. Huang, Q. Zhang, C. Shen, Q. Chen and H. Zhou, *Adv. Mater.*, 2017, 29, 1606774.
- 59 L. Zuo, H. Guo, D. W. Dequilettes, S. Jariwala, N. D. Marco, S. Dong, R. Deblock, D. S. Ginger, B. Dunn and M. Wang, *Sci. Adv.*, 2017, 3, e1700106.
- 60 J. You, Z. Hong, Y. M. Yang, Q. Chen, M. Cai, T. B. Song, C. C. Chen, S. Lu, Y. Liu and H. Zhou, *ACS Nano*, 2014, 8, 1674.
- 61 X. Bao, Y. Wang, Q. Zhu, N. Wang, D. Zhu, J. Wang, A. Yang and R. Yang, *J. Power Sources*, 2015, **297**, 53–58.
- 62 H. Tsai, W. Nie, J.-C. Blancon, C. C. Stoumpos, R. Asadpour, B. Harutyunyan, A. J. Neukirch, R. Verduzco, J. J. Crochet and S. Tretiak, *Nature*, 2016, **536**, 312.
- 63 J. Werner, C. H. Weng, A. Walter, L. Fesquet, J. P. Seif, S. De Wolf, B. Niesen and C. Ballif, *J. Phys. Chem. Lett.*, 2016, 7, 161–166.
- 64 F. Xie, C.-C. Chen, Y. Wu, X. Li, M. Cai, X. Liu, X. Yang and L. Han, *Energy Environ. Sci.*, 2017, **10**, 1942–1949.
- 65 L. Yang, F. Cai, Y. Yan, J. Li, D. Liu, A. J. Pearson and T. Wang, *Adv. Funct. Mater.*, 2017, 27, 1702613.
- 66 S. S. Shin, E. J. Yeom, W. S. Yang, S. Hur, M. G. Kim, J. Im, J. Seo, J. H. Noh and S. I. Seok, *Science*, 2017, 356, 167–171.

- 67 J. Peng, T. Duong, X. Zhou, H. Shen, Y. Wu, H. K. Mulmudi,
  Y. Wan, D. Zhong, J. Li, T. Tsuzuki, K. J. Weber,
  K. R. Catchpole and T. P. White, *Adv. Energy Mater.*, 2017,
  7, 1601768.
- 68 T. Duong, Y. Wu, H. Shen, J. Peng, X. Fu, D. Jacobs, E.-C. Wang, T. C. Kho, K. C. Fong, M. Stocks, E. Franklin, A. Blakers, N. Zin, K. McIntosh, W. Li, Y.-B. Cheng, T. P. White, K. Weber and K. Catchpole, *Adv. Energy Mater.*, 2017, 7, 1700228.
- 69 Z. Qiu, S. Yuan, H. Gong, H. Zhang, X. Qiu, T. Luo, B. Cao and H. Du, *J. Am. Ceram. Soc.*, 2017, **100**, 176–184.
- 70 N. Y. Nia, F. Matteocci, L. Cina and A. Di Carlo, *ChemSusChem*, 2017, **10**, 3854–3860.
- 71 T. Gatti, S. Casaluci, M. Prato, M. Salerno, F. Di Stasio, A. Ansaldo, E. Menna, A. Di Carlo and F. Bonaccorso, *Adv. Funct. Mater.*, 2016, 26, 7443–7453.
- 72 H. Choi, J. Jeong, H.-B. Kim, S. Kim, B. Walker, G.-H. Kim and J. Y. Kim, *Nano Energy*, 2014, 7, 80–85.
- 73 S. Ye, W. Sun, Y. Li, W. Yan, H. Peng, Z. Bian, Z. Liu and C. Huang, *Nano Lett.*, 2015, **15**, 3723–3728.
- 74 N. Arora, M. I. Dar, A. Hinderhofer, N. Pellet, F. Schreiber, S. M. Zakeeruddin and M. Grätzel, *Science*, 2017, 358, 768–771.
- 75 K. Do, H. Choi, K. Lim, H. Jo, J. W. Cho, M. K. Nazeeruddin and J. Ko, *Chem. Commun.*, 2014, **50**, 10971–10974.
- 76 Y. Xu, T. Bu, M. Li, T. Qin, C. Yin, N. Wang, R. Li, J. Zhong,
  H. Li, Y. Peng, J. Wang, L. Xie and W. Huang, *ChemSusChem*, 2017, 10, 2578–2584.
- 77 X. Liu, F. Kong, Z. a. Tan, T. Cheng, W. Chen, T. Yu, F. Guo, J. Chen, J. Yao and S. Dai, *RSC Adv.*, 2016, 6, 87454–87460.
- 78 W. Chen, L. Xu, X. Feng, J. Jie and Z. He, *Adv. Mater.*, 2017, 29, 1603923.
- 79 Y. Bai, S. Xiao, C. Hu, T. Zhang, X. Y. Meng, Q. Li, Y. L. Yang,
  K. S. Wong, H. N. Chen and S. H. Yang, *Nano Energy*, 2017,
  34, 58–68.
- 80 J. B. Zhang, B. Xu, L. Yang, C. Q. Ruan, L. Q. Wang, P. Liu, W. Zhang, N. Vlachopoulos, L. Kloo, G. Boschloo, L. C. Sun, A. Hagfeldt and E. M. J. Johansson, *Adv. Energy Mater.*, 2018, 8, 1701209.
- 81 H. Zhang, H. Wang, S. T. Williams, D. Xiong, W. Zhang, C. C. Chueh, W. Chen and A. K. Jen, *Adv. Mater.*, 2017, 29, 1–8.
- 82 A. Mei, X. Li, L. Liu, Z. Ku, T. Liu, Y. Rong, M. Xu, M. Hu, J. Chen and Y. Yang, *Science*, 2014, 345, 295.
- 83 J. Chen, Y. Rong, A. Mei, Y. Xiong, T. Liu, Y. Sheng, P. Jiang, L. Hong, Y. Guan, X. Zhu, X. Hou, M. Duan, J. Zhao, X. Li and H. Han, *Adv. Energy Mater.*, 2016, 6, 1502009.
- 84 X. Jiang, Y. Xiong, A. Mei, Y. Rong, Y. Hu, L. Hong, Y. Jin, Q. Liu and H. Han, *J. Phys. Chem. Lett.*, 2016, 7, 4142–4146.
- 85 Z. Liu, T. Shi, Z. Tang, B. Sun and G. Liao, *Nanoscale*, 2016, 8, 7017–7023.
- 86 L. Huang, Z. Hu, J. Xu, K. Zhang, J. Zhang and Y. Zhu, Sol. Energy Mater. Sol. Cells, 2015, 141, 377–382.
- 87 X. Huang, Z. Hu, J. Xu, P. Wang, L. Wang, J. Zhang and
   Y. Zhu, Sol. Energy Mater. Sol. Cells, 2017, 164, 87–92.
- 88 J. Kim, J. S. Yun, Y. Cho, D. S. Lee, B. Wilkinson, A. M. Soufiani, X. Deng, J. Zheng, A. Shi, S. Lim, S. Chen,

Z. Hameiri, M. Zhang, C. F. J. Lau, S. Huang, M. A. Green and A. W. Y. Ho-Baillie, *ACS Energy Lett.*, 2017, 2, 1978– 1984.

- 89 F. Zhang, W. Shi, J. Luo, N. Pellet, C. Yi, X. Li, X. Zhao, T. J. S. Dennis, X. Li, S. Wang, Y. Xiao, S. M. Zakeeruddin, D. Bi and M. Grätzel, *Adv. Mater.*, 2017, 29, 1606806.
- 90 N. Aeineh, E. M. Barea, A. Behjat, N. Sharifi and I. Mora-Sero, *ACS Appl. Mater. Interfaces*, 2017, **9**, 13181–13187.
- 91 M. Hambsch, Q. Lin, A. Armin, P. L. Burn and P. Meredith, J. Mater. Chem. A, 2016, 4, 13830–13836.
- 92 Y. Zhou and N. P. Padture, ACS Energy Lett., 2017, 2, 2166–2176.
- 93 Z. Zhou, Z. Wang, Y. Zhou, S. Pang, D. Wang, H. Xu, Z. Liu, N. P. Padture and G. Cui, *Angew. Chem., Int. Ed.*, 2015, 54, 9705–9709.
- 94 Q. Hu, H. Wu, J. Sun, D. Yan, Y. Gao and J. Yang, *Nanoscale*, 2016, **8**, 5350–5357.
- 95 Y. Hou, X. Du, S. Scheiner, D. P. McMeekin, Z. Wang, N. Li, M. S. Killian, H. Chen, M. Richter, I. Levchuk, N. Schrenker, E. Spiecker, T. Stubhan, N. A. Luechinger, A. Hirsch, P. Schmuki, H. P. Steinruck, R. H. Fink, M. Halik, H. J. Snaith and C. J. Brabec, *Science*, 2017, 358, 1192–1197.
- 96 A. Luque and S. Hegedus, *Handbook of photovoltaic science* and engineering, John Wiley & Sons, 2011.
- 97 W. T. Deng, X. X. Liang, P. S. Kubiak and P. J. Cameron, *Adv. Energy Mater.*, 2018, 8, 1701544.
- 98 P. P. Boix, K. Nonomura, N. Mathews and S. G. Mhaisalkar, *Mater. Today*, 2014, **17**, 16–23.
- 99 W.-J. Yin, J.-H. Yang, J. Kang, Y. Yan and S.-H. Wei, *J. Mater. Chem. A*, 2015, **3**, 8926–8942.
- 100 G. E. Eperon and D. S. Ginger, Nat. Energy, 2016, 1, 16109.
- 101 X. Tong, F. Lin, J. Wu and Z. M. Wang, *Adv. Sci.*, 2016, 3, 1500201.
- 102 V. Adinolfi, W. Peng, G. Walters, O. M. Bakr and E. H. Sargent, *Adv. Mater.*, 2018, 30, 1700764.
- 103 M. E. Calvo, J. Mater. Chem. A, 2017, 5, 20561–20578.
- 104 A. B. Djurišić, F. Z. Liu, H. W. Tam, M. K. Wong, A. Ng, C. Surya, W. Chen and Z. B. He, *Prog. Quantum Electron.*, 2017, 53, 1–37.
- 105 M. L. Petrus, J. Schlipf, C. Li, T. P. Gujar, N. Giesbrecht, P. Muller-Buschbaum, M. Thelakkat, T. Bein, S. Huttner and P. Docampo, *Adv. Energy Mater.*, 2017, 7, 1700264.
- 106 Y. Yang and J. B. You, Nature, 2017, 544, 155.
- 107 M. Ye, X. Hong, F. Zhang and X. Liu, *J. Mater. Chem. A*, 2016, 4, 6755–6771.
- 108 B. Conings, J. Drijkoningen, N. Gauquelin, A. Babayigit, J. D'Haen, L. D'Olieslaeger, A. Ethirajan, J. Verbeeck, J. Manca, E. Mosconi, F. D. Angelis and H.-G. Boyen, Adv. Energy Mater., 2015, 5, 1500477.
- 109 B. Philippe, B.-W. Park, R. Lindblad, J. Oscarsson, S. Ahmadi, E. M. J. Johansson and H. Rensmo, *Chem. Mater.*, 2015, 27, 1720–1731.
- 110 J. M. Frost, K. T. Butler, F. Brivio, C. H. Hendon, M. van Schilfgaarde and A. Walsh, *Nano Lett.*, 2014, **14**, 2584–2590.
- 111 H. S. Kim, J. Y. Seo and N. G. Park, *ChemSusChem*, 2016, 9, 2528.

- 112 A. M. A. Leguy, Y. Hu, M. Campoy-Quiles, M. I. Alonso,
  O. J. Weber, P. Azarhoosh, M. van Schilfgaarde,
  M. T. Weller, T. Bein, J. Nelson, P. Docampo and
  P. R. F. Barnes, *Chem. Mater.*, 2015, 27, 3397–3407.
- 113 T. Leijtens, G. E. Eperon, S. Pathak, A. Abate, M. M. Lee and H. J. Snaith, *Nat. Commun.*, 2013, 4, 2885.
- 114 Y. Chen, Y. Sun, J. Peng, J. Tang, K. Zheng and Z. Liang, *Adv. Mater.*, 2018, **30**, 1703487.
- 115 H. Tsai, W. Nie, J. C. Blancon, C. C. Stoumpos, R. Asadpour, B. Harutyunyan, A. J. Neukirch, R. Verduzco, J. J. Crochet, S. Tretiak, L. Pedesseau, J. Even, M. A. Alam, G. Gupta, J. Lou, P. M. Ajayan, M. J. Bedzyk and M. G. Kanatzidis, *Nature*, 2016, **536**, 312–316.
- M. Saliba, T. Matsui, K. Domanski, J. Y. Seo,
  A. Ummadisingu, S. M. Zakeeruddin, J. P. Correabaena,
  W. R. Tress, A. Abate, A. Hagfeldt and M. Grätzel, *Science*, 2016, 354, 206.
- 117 A. Agresti, S. Pescetelli, L. Cinà, D. Konios, G. Kakavelakis,E. Kymakis and A. D. Carlo, *Adv. Funct. Mater.*, 2016, 26, 2686–2694.
- 118 D. Bi, G. Boschloo, S. Schwarzmuller, L. Yang,
  E. M. Johansson and A. Hagfeldt, *Nanoscale*, 2013, 5, 11686–11691.
- 119 B. Li, Y. Zhang, L. Zhang and L. Yin, *Adv. Mater.*, 2017, **29**, 1701221.
- 120 J. Gong, S. B. Darling and F. Q. You, *Energy Environ. Sci.*, 2015, **8**, 1953–1968.
- 121 S. Maniarasu, T. B. Korukonda, V. Manjunath, E. Ramasamy, M. Ramesh and G. Veerappan, *Renewable Sustainable Energy Rev.*, 2018, 82, 845–857.

- 122 T. Hu, T. Becker, N. Pourdavoud, J. Zhao, K. O. Brinkmann, R. Heiderhoff, T. Gahlmann, Z. Huang, S. Olthof, K. Meerholz, D. Tobbens, B. Cheng, Y. Chen and T. Riedl, *Adv. Mater.*, 2017, 29, 1606656.
- 123 A. Babayigit, A. Ethirajan, M. Muller and B. Conings, *Nat. Mater.*, 2016, **15**, 247–251.
- 124 D. Cortecchia, H. A. Dewi, J. Yin, A. Bruno, S. Chen, T. Baikie, P. P. Boix, M. Grätzel, S. Mhaisalkar, C. Soci and N. Mathews, *Inorg. Chem.*, 2016, 55, 1044–1052.
- 125 T. Krishnamoorthy, H. Ding, C. Yan, W. L. Leong, T. Baikie, Z. Y. Zhang, M. Sherburne, S. Li, M. Asta, N. Mathews and S. G. Mhaisalkar, *J. Mater. Chem. A*, 2015, 3, 23829–23832.
- 126 P. C. Harikesh, H. K. Mulmudi, B. Ghosh, T. W. Goh, Y. T. Teng, K. Thirumal, M. Lockrey, K. Weber, T. M. Koh, S. Z. Li, S. Mhaisalkar and N. Mathews, *Chem. Mater.*, 2016, 28, 7496–7504.
- 127 G. Volonakis, M. R. Filip, A. A. Haghighirad, N. Sakai,B. Wenger, H. J. Snaith and F. Giustino, *J. Phys. Chem. Lett.*, 2016, 7, 1254–1259.
- 128 Z. H. Sun, A. R. Zeb, S. J. Liu, C. M. Ji, T. Khan, L. Li, M. C. Hong and J. H. Luo, *Angew. Chem., Int. Ed.*, 2016, 55, 11854–11858.
- 129 S. J. Lee, S. S. Shin, Y. C. Kim, D. Kim, T. K. Ahn, J. H. Noh, J. Seo and S. I. Seok, *J. Am. Chem. Soc.*, 2016, **138**, 3974– 3977.
- 130 W. Q. Liao, D. W. Zhao, Y. Yu, C. R. Grice, C. L. Wang, A. J. Cimaroli, P. Schulz, W. W. Meng, K. Zhu, R. G. Xiong and Y. F. Yan, *Adv. Mater.*, 2016, **28**, 9333.